

# **Pressure sensors**

# C32 series

Series/Type: Absolute low pressure sensor die C32/1 (open bridge)

Ordering code: B58600E32\*\*B615/...B646

Date: 2021-03-08

Version: 6

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## **Applications**

- Medical devices
- Automotive
- Medical

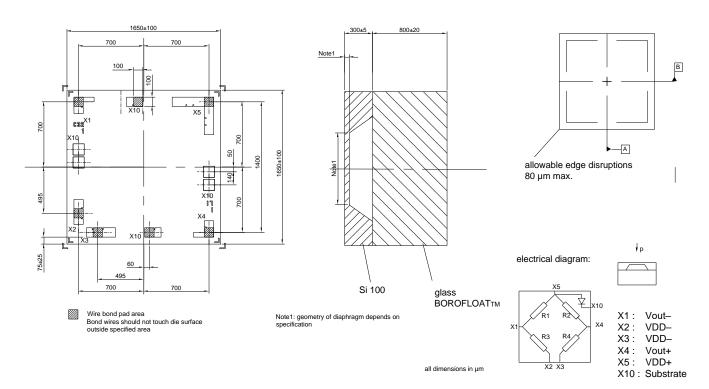
### **Features**

- Piezoresistive MEMS technology
- Small dimensions: 1.65 x 1.65 mm
- Square diaphragm
- Measured media (front side):
  Dry non-aggressive gases.
  Unsuitable for substances which react with glass, silicon or aluminum.
- Wheatstone bridge with mV output, ratiometric to supply voltage
- Rated pressure range: 0.4 up to 1.0 bar
- Outstanding long-term stability

## **Delivery mode**

■ Tape, Tray

### **Dimensional drawings**





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### **Technical data**

## **Absolute maximum ratings**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Supply voltage							
Maximum supply voltage	V <sub>DD</sub>	Without damage 1)		10	V		
Temperature ranges							
Operating temperature range	Ta	2) —40			150	°C	
Storage temperature range	_	3)	-50		165	°C	
	T <sub>st</sub>	For t <2 h	-50		175	°C	
Pressure ranges							
Operating pressure ranges	pr	Absolute pressure 4) 0 0.4		0 1.0	bar		
Over pressure	pov	Absolute pressure 5)	S	See next table		p <sub>r</sub>	
Burst pressure	Pburst	Absolute pressure 6)	S	See next table			

## **Electrical specifications**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Supply voltage / bridge resistance	е		•	•	•	1	
Operating supply voltage	V <sub>DD</sub>	7)	1.0		5.0	V	
Total bridge resistance	Rb	@ 25 °C <sup>8)</sup>	2.6 3.3 4.0		4.0	kΩ	
Temperature coefficient	αRb	- @ 25 °C <sup>9)</sup>	2.0	2.3	2.7	10 <sup>-3</sup> /K	
of total bridge resistance	$\beta_{Rb}$	- @ 25 C <sup>-</sup> /	0	5	8	10 <sup>-6</sup> /K <sup>2</sup>	
Output signal @ V <sub>DD</sub> = 5 V							
Offset	Vo	@ 25 °C <sup>10)</sup>	@ 25 °C <sup>10)</sup> -30		30	mV	
Sensitivity	S	@ 25 °C <sup>13)</sup>	S	See next table			
Temperature coefficient of offset	TCVo+	- Unglued <sup>11)</sup>	S	See next table			
	TCVo-	- Ongiuea ···	S	See next table			
Temperature coefficient	αs	- @ 25 °C <sup>15)</sup>	-2.5	-2.1	-1.9	10 <sup>-3</sup> /K	
of the sensitivity	βs	- @ 25 C <sup>19</sup> /	0	5	8	10 <sup>-6</sup> /K <sup>2</sup>	
Pressure hysteresis	рнуѕ	16)	6) -0.1 0.1		0.1	% FS <sup>12)</sup>	
Long-term stability (Full scale no	rmal output	FSON = 120 mV)					
Temperature hysteresis of offset	THV <sub>0</sub>	17)	-0.2	±0.1	0.2	% FSON	
Temperature cycle drift of offset	TCDV <sub>0</sub>	17)	-0.1	±0.05	0.1	% FSON	
High temperature drift of offset	HTDV <sub>0</sub>	17) -0.25 ±0.05		0.25	% FSON		
Long term stability of offset	LTSV <sub>0</sub>	17)	-0.3	±0.1	0.3	% FSON	



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## Operating pressures and ordering codes

Parameter @ 25 °C, V <sub>DD</sub> = 5 V	Symbol	Тур.	Units
Operating pressure 4)	Pr	1.0	bar
Temperature coefficient	TCV <sub>0</sub> <sup>-</sup>	-4 / 8 / 20	μV/V/K
of offset <sup>11)</sup> [min/typ/max]	TCV <sub>0</sub> +	-3/3/9	μV/V/K
Sensitivity 13) [min/typ/max]	S	130/160/190	mV/bar
Nonlinearity 14) [typ/max]	L	±0.2/±0.3	% FS <sup>12)</sup>
Over pressure 5) [min]	Pov	3	bar
Burst pressure <sup>6)</sup> [min]	Pburst	5	bar
Product type		AEA 1.000 C32/1 F00 G08 N	
Ordering code Delivery form on tape		B58600E3214B615	
Ordering code Delivery in tray		B58600E3214B646	

Convers	sion table	mbar	bar	Pa	kPa	Psi	Torr	mWS
mbar	(hPa)	1	0.001	100	0.100	0.0145	0.750	0.0102
bar		1000	1	100000	100	14.500	750	10.200
Pa	(N/m <sup>2)</sup>	0.010	0.00001	1	0.001	0.000145	0.00750	0.000102
kPa		10.000	0.0100	1000	1	0.145	7.50	1.02
Psi	(Lb/inch <sup>2)</sup>	68.9	0.0689	6895	6.89	1	51.7	0.703
Torr		1.33	0.00133	133	0.133	0.0193	1	0.0136
mWS		98.100	0.0981	9807	9.81	1.42	73.6	1

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### **Symbols and Terms**

### 1) Maximum power supply V<sub>DD</sub>

This is the maximal allowed voltage, which may be applied to the piezoresistive bridge circuit without damage.

#### 2) Operating temperature range Ta

This is the operating temperature range  $T_{a,min}$  to  $T_{a,max}$ . Because most of the sensor parameters depend on assembling conditions like glueing, wire bonding etc, the die has to be tested over the operating temperature range by the customer fully assembled. For design verification and process control, samples, mounted in TDK Sensors standard transducer packages, are tested over the temperature range of  $T_{a,min}$  to  $T_{a,max}$ .

#### 3) Storage temperature range T<sub>st</sub>

If the pressure sensor dies are stored in the temperature range  $T_{\text{st,min}}$  to  $T_{\text{st,max}}$  without applied voltage power supply, this will not affect the performance of the pressure sensor dies.

### 4) Operating pressure range pr

In the operating pressure range 0 to pr,max the pressure sensor die output characteristic is as defined in this specification.

#### 5) Over pressure pov

Pressure cycles in the pressure range 0 to pov do not affect the performance of the pressure sensor dies.

#### 6) Burst pressure pburst

Up to the burst pressure pourst the diaphragm of the sensor die will not be destroyed mechanically.

#### 7) Operating power supply V<sub>DD</sub>

The pressure sensor parameters are defined for a power supply voltage of  $V_{DD} = 5$  V. In the operating power supply voltage range  $V_{DD,min}$  to  $V_{DD,max}$  the ratiometric parameters  $r(V_{DD})$  like sensitivity, offset voltage and the temperature coefficient of the offset voltage are defined by:

$$r(V_{DD}) = r(5[V]) \frac{V_{DD}}{5[V]}$$

#### 8) Total bridge resistance Rb

The total bridge resistance is defined between pad X5 and X2, X3 (see the dimensional drawing in this data sheet) of the opened piezoresistive bridge circuit. The total bridge resistance is in a good approximation the output impedance of the piezoresistive bridge circuit. This parameter is tested completely on a wafer (wafer level test measurement).

#### <sup>9)</sup> Temperature coefficients of resistance $\alpha_{Rb}$ and $\beta_{Rb}$ :

The temperature coefficients of resistance are tested for design verification on samples, mounted in TDK Sensors standard transducer package over the temperature range  $T_{a,min}$  to  $T_{a,max}$  with  $T_R = 25$  °C.

The temperature coefficients of first and second order are defined with the polynomial:

$$R_b(T) = R_b(T = 25^{\circ}C)[1 + \alpha_{Rb}(T - 25^{\circ}C) + \beta_{Rb}(T - 25^{\circ}C)^2]$$

The coefficients  $\alpha_{Rb}$  and  $\beta_{Rb}$  are calculated using the three measurement points of  $R_b(T)$  at  $T_{a,min}$ ,  $T_R$  and  $T_{a,max}$ .

### 10) Offset voltage V<sub>0</sub>

The offset voltage  $V_0$  is the output voltage  $V_{out}(p=0$  bar abs) at zero absolute pressure and for a bridge voltage power supply  $V_{DD}=5$  V. Before anodic glass bonding the offset voltage is tested completely on a wafer (wafer level test measurement) with limits -25 mV  $< V_0 < 25$  mV.

For design verification  $V_0$  is measured on samples, mounted in TDK Sensors standard transducer package by extrapolating the output characteristic to zero bar.

Since the offset voltage depends on several assembling conditions, this parameter has to be verified by the customer with his assembling possibilities.

## $^{11)}$ Temperature coefficients of offset voltage TCV $_{0}$

The temperature coefficients of offset voltage are defined for a bridge voltage power supply  $V_{DD} = 5 \text{ V}$ .

These parameters strongly depend on assembly conditions like gluing, wire bonding etc.

The temperature coefficients of offset voltage are tested for design verification on samples, mounted in TDK Sensors standard transducer package over the temperature range  $T_{a,min}$  to  $T_{a,max}$  with  $T_R = 25$  °C.

TCV<sub>0+</sub> and TCV<sub>0-</sub> are defined for the measurement temperature range by:

$$TCVo^{+} = \frac{1}{V_{DD}} \frac{V_{o}(T_{a,max}) - V_{o}(25^{\circ}C)}{T_{a,max} - 25^{\circ}C} \qquad TCVo^{-} = \frac{1}{V_{DD}} \frac{V_{o}(T_{a,min}) - V_{o}(25^{\circ}C)}{T_{a,min} - 25^{\circ}C}$$

Since the  $TCV_0$  depends on several assembling conditions, this parameter has to be verified by the customer with his assembling possibilities.

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#### 12) Full scale value FS

$$FS = V_{out}(p_{r max}) - V_{o}$$

#### 13) Sensitivity S

The sensitivity is defined for a bridge voltage power supply V<sub>DD</sub> = 5 V. It can be determined by the formula:

$$S = \frac{V_{out}(p_{r max}) - V_{o}}{p_{r max}}$$

This parameter is tested for process control on samples, mounted in TDK Sensors standard transducer package.

#### 14) Nonlinearity L

This parameter may be influenced by assembly.

The nonlinearity is measured using the endpoint method. Assuming a characteristic, this can be approximated by a polynomial of second order, where the maximum is at  $p_x = p_{rmax}/2$ . The nonlinearity is defined at  $p_x = p_{rmax}/2$ , using the equation:

$$L = \frac{V_{out}(p_{x}) - V_{o}}{V_{out}(p_{r max}) - V_{o}} - \frac{p_{x}}{p_{r max}}$$

This parameter is tested for process control on samples, mounted in TDK Sensors standard transducer package.

#### <sup>15)</sup> Temperature coefficient of sensitivity $\alpha_S$ and $\beta_S$ :

These parameters may be influenced by assembly.

The temperature coefficients of sensitivity are tested for design verification on samples, mounted in TDK Sensors standard transducer package over the temperature range  $T_{a,min}$  to  $T_{a,max}$  with  $T_R = 25$  °C.

The temperature coefficients of first and second order are defined with the polynomial:

$$S(T) = S(T = 25^{\circ}C)[1 + \alpha_S(T - 25^{\circ}C) + \beta_S(T - 25^{\circ}C)^2]$$

The coefficients  $\alpha_S$  and  $\beta_S$  are calculated using the three measurement points of S(T) at T<sub>a,min</sub>, T<sub>R</sub> and T<sub>a,max</sub>.

#### 16) Pressure hysteresis p<sub>Hvs</sub>

The pressure hysteresis is the difference between output voltages at constant pressure and constant temperature while applying a pressure cycle with pressure steps of p<sub>r, min</sub>, p<sub>1</sub>, p<sub>2</sub>, p<sub>3</sub>, p<sub>r,max</sub>, p<sub>3</sub>, p<sub>2</sub>, p<sub>1</sub>, p<sub>r, min</sub>:

$$p_{Hys} = \frac{V_{out,2}(p_k) - V_{out,1}(p_k)}{FS}$$

With k = min, 1, 2, 3, max. The pressure steps are:  $p_{rmin} = 0$ ,  $p_1 = 0.25 \cdot p_{r,max}$ ,  $p_2 = 0.5 \cdot p_{r,max}$ ,  $p_3 = 0.75 \cdot p_{r,max}$ ,  $p_{r,max}$ . This parameter is tested for design verification on samples, mounted in TDK Sensors standard transducer package. Since the  $p_{Hys}$  depends on several assembling conditions, this parameter has to be verified by the customer with his assembling possibilities.

### 17) Reliability data

For long-term stability of offset voltage LTSV $_0$  please refer to the defined TDK Sensors standard AS100001 in chapter "Long term stability parameter" on the internet. Since the LTSV $_0$  depends on several assembling conditions, this parameter has to be verified by the customer with his assembling possibilities.



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### Cautions and warnings

#### Storage (general)

All pressure sensors should be stored in their original packaging. They should not be placed in harmful environments such as corrosive gases, or be exposed to heat or direct sunlight, which may cause deformations. Similar effects may result from extreme storage temperatures and climatic conditions. Avoid storing the sensor dies in an environment where condensation may form, or in a location exposed to corrosive gases, which will adversely affect their performance. Plastic materials should not be used for wrapping/packing when storing or transporting these dies, as they may become charged. Pressure sensor dies should be used soon after opening their seal and packaging.

#### Storage conditions

Used materials for storage should be ESD protective according JESD625, non-outgassing, and chemically stable. Furthermore, the following storage conditions should be preserved:

- 1. Storage in cabinets (if shipment package is opened):
  - a. Atmosphere: inert gas, dry air or dry nitrogen
  - b. Temperature range (in cabinet): 20±3 °C
  - c. Relative humidity range (in cabinet): < 40 %
  - d. Particle count (in cabinet): Class 6 per ISO 14644:1999 (equivalent FED STD 209E Class 1000)
  - e. Shelf life under these conditions: 24 months for deliveries in trays
  - f. Shelf life under these conditions: 12 months for deliveries on tape
- 2. Storage in containers (if shipment package is sealed):
  - a. Sealed as delivered or backfilled with inert gas, dry air or dry nitrogen and re-sealed
  - b. Temperature range: 20±3 °C
  - c. Relative humidity range: < 50 %
  - d. Particle count (during backfill): Class 6 per ISO 14644:1999 (equivalent FED STD 209E Class 1000)
  - e. Shelf life under these conditions: 12 months for deliveries in trays
  - f. Shelf life under these conditions: 6 months for deliveries on tape

After delivery, the product can be stored under specific conditions for the specified shelf life. This listing does not claim to be complete, but merely reflects the experience of TDK Electronics AG

### Operation (general)

Media compatibility with the pressure sensors must be ensured to prevent their failure. The use of other media can cause damage and malfunction. Never use pressure sensors in atmospheres containing explosive liquids or gases.

Ensure pressure equalization to the environment, if gauge pressure sensors are used. Avoid operating the pressure sensors in an environment where condensation may form, or in a location exposed to corrosive gases. These environments adversely affect their performance.

If the operating pressure is above the rated overpressure range, it may change the output characteristics. This may also happen with pressure sensor dies if an incorrect mounting method is used. Be sure that the applicable pressure does not exceed the overpressure, as it may damage the pressure sensor.

Do not exceed the maximum rated supply voltage nor the rated storage temperature range, as it may damage the pressure sensor.

Temperature variations in both the ambient conditions and the media (liquid or gas) can affect the accuracy of the output signal from the pressure sensors. Be sure to check the operating temperature range and thermal error specification of the pressure sensors to determine their suitability for the application.

Connections must be wired in accordance with the terminal assignment specified in the data sheets. Care should be taken as reversed pin connections can damage the pressure transmitters or degrade their performance. Contact between the pressure sensor terminals and metals or other materials may cause errors in the output characteristics.

### Design notes (dies)

This specification describes the mechanical, electrical and physical requirements of a piezoresistive sensor die for measuring pressure. The specified parameters are valid for the pressure sensor die with pressure application either to the front or back side of the diaphragm as described in the data sheet. Pressure application to the other side may result in differing data. Most of the parameters are influenced by assembly conditions. Hence, these parameters and the reliability have to be specified for each specific application and tested over its temperature range by the customer.



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#### Handling/Mounting (dies)

Pressure sensor dies should be handled appropriately and not be touched with bare hands. They should only be picked up manually by the sides using tweezers. Their top surface should never be touched with tweezers. Latex gloves should not be used for handling them, as this will inhibit the curing of the adhesive used to bond the die to the carrier. When handling, be careful to avoid cuts caused by the sharp-edged terminals. The sensor die must not be contaminated during manufacturing processes (gluing, soldering, silk-screen process).

The package of pressure sensor dies should not to be opened until the die is mounted and should be closed after use. The sensor die must not be cleaned. The sensor die must not be damaged during the assembly process (especially scratches on the diaphragm).

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## **Important notes**

8. The trade names EPCOS, CarXield, CeraCharge, CeraDiode, CeraLink, CeraPad, CeraPlas, CSMP, CTVS, DeltaCap, DigiSiMic, ExoCore, FilterCap, FormFit, LeaXield, MiniBlue, MiniCell, MKD, MKK, ModCap, MotorCap, PCC, PhaseCap, PhaseCube, PhaseMod, PhiCap, PowerHap, PQSine, PQvar, SIFERRIT, SIFI, SIKOREL, SilverCap, SIMDAD, SiMic, SIMID, SineFormer, SIOV, ThermoFuse, WindCap, XieldCap are trademarks registered or pending in Europe and in other countries. Further information will be found on the Internet at www.tdk-electronics.tdk.com/trademarks.

Release 2020-06